LM124/LM224/LM324/LM2902
Low Power Quad Operational Amplifiers

General Description
The LM124 series consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits which now can be more easily implemented in single power supply systems. For example, the LM124 series can be directly operated off of the standard ±5V power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional ±15V power supplies.

Unique Characteristics
- In the linear mode the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage
- The unity gain cross frequency is temperature compensated
- The input bias current is also temperature compensated

Advantages
- Eliminates need for dual supplies
- Four internally compensated op amps in a single package
- Allows directly sensing near GND and \( V_{OUT} \) also goes to GND
- Compatible with all forms of logic
- Power drain suitable for battery operation

Features
- Internally frequency compensated for unity gain
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1 MHz (temperature compensated)
- Wide power supply range: Single supply 3V to 32V or dual supplies ±1.5V to ±16V
- Very low supply current drain (700 \( \mu A \))—essentially independent of supply voltage
- Low input biasing current: 45 nA (temperature compensated)
- Low input offset voltage: 2 mV and offset current 5 nA
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing: 0V to \( V^+ \) — 1.5V

Connection Diagram

See NS Package Number J14A, M14A or N14A

Order Number LM124AE/883 or LM124E/883
See NS Package Number E20A

Order Number LM124AW/883 or LM124W/883
See NS Package Number W14B

*LM124A available per JM38510/11006
**LM124 available per JM38510/11005

© 1995 National Semiconductor Corporation TL/H/9299 Printed in U. S. A.
### Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

(Note 9)

<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage, V^+</td>
<td>32V</td>
<td>26V</td>
<td>Storage Temperature Range</td>
<td>−65°C to +150°C</td>
</tr>
<tr>
<td>Differential Input Voltage</td>
<td>32V</td>
<td>26V</td>
<td>Lead Temperature (Soldering, 10 seconds)</td>
<td>260°C</td>
</tr>
<tr>
<td>Input Voltage</td>
<td>−0.3V to +32V</td>
<td>−0.3V to +26V</td>
<td>Soldering Information</td>
<td>Dual-In-Line Package</td>
</tr>
<tr>
<td>Input Current</td>
<td>(V_in &lt; −0.3V) (Note 3)</td>
<td>50 mA</td>
<td>Soldering (10 seconds)</td>
<td>260°C</td>
</tr>
<tr>
<td>Power Dissipation (Note 1)</td>
<td>Molded DIP</td>
<td>1130 mW</td>
<td>Small Outline Package</td>
<td>Vapor Phase (60 seconds)</td>
</tr>
<tr>
<td></td>
<td>Cavity DIP</td>
<td>1250 mW</td>
<td></td>
<td>Infrared (15 seconds)</td>
</tr>
<tr>
<td></td>
<td>Small Outline Package</td>
<td>800 mW</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Output Short-Circuit to GND</td>
<td></td>
<td></td>
<td>See AN-450 “Surface Mounting Methods and Their Effect on Product Reliability” for other methods of soldering surface mount devices.</td>
<td></td>
</tr>
</tbody>
</table>

### Supply Voltage

- **V_a**: 32V 26V
- **V_b**: 0V to 32V 0V to 26V

### Lead Temperature (Soldering, 10 seconds)

- **260°C** 260°C

### Input Voltage

- **V_a**: 0V to 32V 0V to 26V

### Soldering Information

- **Dual-In-Line Package**: 50 mA
- **Small Outline Package**: 50 mA

### Operating Temperature Range

- **LM324/LM324A**: 0°C to +150°C
- **LM224/LM224A**: −25°C to +150°C
- **LM124/ LM124A**: −55°C to +125°C

### Electrical Characteristics

#### V^+ = +5.0V, (Note 4), unless otherwise stated

<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>Parameter Conditions</td>
<td>Min</td>
<td>Typ</td>
<td>Max</td>
<td>Min</td>
<td>Typ</td>
</tr>
<tr>
<td>Input Offset Voltage</td>
<td>(Note 5) T_A = 25°C</td>
<td>1</td>
<td>2</td>
<td>1</td>
<td>3</td>
</tr>
<tr>
<td>Input Bias Current (Note 6)</td>
<td>I_{IN(+)} or I_{IN(-), V_CM = 0V, T_A = 25°C}</td>
<td>20</td>
<td>50</td>
<td>40</td>
<td>80</td>
</tr>
<tr>
<td>Input Offset Current</td>
<td>I_{IN(+)} - I_{IN(-), V_CM = 0V, T_A = 25°C}</td>
<td>2</td>
<td>10</td>
<td>2</td>
<td>15</td>
</tr>
<tr>
<td>Input Common-Mode Voltage Range (Note 7)</td>
<td>V^+ = 30V, (LM2902, V^+ = 26V), T_A = 25°C</td>
<td>0</td>
<td>V^+−1.5</td>
<td>0</td>
<td>V^+−1.5</td>
</tr>
<tr>
<td>Supply Current</td>
<td>Over Full Temperature Range R_L = \infty On All Op Amps</td>
<td>1.5</td>
<td>3</td>
<td>1.5</td>
<td>3</td>
</tr>
<tr>
<td>Large Signal Voltage Gain</td>
<td>V^+ = 15V, R_L ≥ 2kΩ, (V_O = 1V to 11V), T_A = 25°C</td>
<td>0.7</td>
<td>1.2</td>
<td>0.7</td>
<td>1.2</td>
</tr>
<tr>
<td>Common-Mode Rejection Ratio</td>
<td>DC, V_CM = 0V to V^+ − 1.5V, T_A = 25°C</td>
<td>70</td>
<td>85</td>
<td>70</td>
<td>85</td>
</tr>
<tr>
<td>Power Supply Rejection Ratio</td>
<td>V^+ = 5V to 50V, (LM2902, V^+ = 5V to 26V), T_A = 25°C</td>
<td>65</td>
<td>100</td>
<td>65</td>
<td>100</td>
</tr>
</tbody>
</table>
## Electrical Characteristics

V^+ = +5.0V (Note 4) unless otherwise stated (Continued)

<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>Amplifier-to-Amplifier Coupling (Note 6)</td>
<td>f = 1 kHz to 20 kHz, T_A = 25°C (Input Referred)</td>
<td>−120</td>
<td>−120</td>
<td>−120</td>
<td>−120</td>
<td>−120</td>
<td>−120</td>
<td>dB</td>
</tr>
<tr>
<td>Output Current Source</td>
<td>V^+ = 1V, V_in = 0V, V^− = 15V, V_C − 2V, T_A = 25°C</td>
<td>20</td>
<td>40</td>
<td>20</td>
<td>40</td>
<td>20</td>
<td>40</td>
<td>mA</td>
</tr>
<tr>
<td>Sink</td>
<td>V^+ = 1V, V_in = 0V, V^− = 15V, V_C − 2V, T_A = 25°C</td>
<td>10</td>
<td>20</td>
<td>10</td>
<td>20</td>
<td>10</td>
<td>20</td>
<td>μA</td>
</tr>
<tr>
<td>Short Circuit to Ground</td>
<td>(Note 2) V^+ = 15V, T_A = 25°C</td>
<td>40</td>
<td>60</td>
<td>40</td>
<td>60</td>
<td>40</td>
<td>60</td>
<td>mA</td>
</tr>
<tr>
<td>Input Offset Voltage</td>
<td>(Note 5)</td>
<td>4</td>
<td>4</td>
<td>5</td>
<td>7</td>
<td>9</td>
<td>10</td>
<td>mV</td>
</tr>
<tr>
<td>Input Offset Voltage Drift</td>
<td>R_S = 0Ω</td>
<td>7</td>
<td>20</td>
<td>7</td>
<td>20</td>
<td>7</td>
<td>30</td>
<td>μV/°C</td>
</tr>
<tr>
<td>Input Offset Current</td>
<td>I_{IN(+)} − I_{IN(−)}, V_{CM} = 0V</td>
<td>30</td>
<td>30</td>
<td>75</td>
<td>100</td>
<td>150</td>
<td>45</td>
<td>nA</td>
</tr>
<tr>
<td>Input Offset Current Drift</td>
<td>R_S = 0Ω</td>
<td>10</td>
<td>200</td>
<td>10</td>
<td>200</td>
<td>10</td>
<td>300</td>
<td>pA/°C</td>
</tr>
<tr>
<td>Input Bias Current</td>
<td>I_{IN(+)} or I_{IN(−)}</td>
<td>40</td>
<td>100</td>
<td>40</td>
<td>100</td>
<td>40</td>
<td>300</td>
<td>nA</td>
</tr>
<tr>
<td>Input Common-Mode Voltage Range (Note 7)</td>
<td>V^+ = +30V (LM2902, V^+ = 26V)</td>
<td>0</td>
<td>V^+ − 2</td>
<td>0</td>
<td>V^+ − 2</td>
<td>0</td>
<td>V^+ − 2</td>
<td>V</td>
</tr>
<tr>
<td>Large Signal Voltage Gain</td>
<td>V^+ = +15V (V_O Swing = 1V to 11V)</td>
<td>25</td>
<td>25</td>
<td>15</td>
<td>25</td>
<td>15</td>
<td>15</td>
<td>V/mV</td>
</tr>
<tr>
<td>Output Voltage Swing</td>
<td>V^+ = 30V (LM2902, V^+ = 26V)</td>
<td>26</td>
<td>26</td>
<td>26</td>
<td>26</td>
<td>26</td>
<td>22</td>
<td>V</td>
</tr>
<tr>
<td>V^+ = 5V, R_L = 10 kΩ</td>
<td>V^+ = 5V, R_L = 10 kΩ</td>
<td>5</td>
<td>20</td>
<td>5</td>
<td>20</td>
<td>5</td>
<td>20</td>
<td>mV</td>
</tr>
<tr>
<td>V^+ = 1V, V_C = 0V, R_L = 2 kΩ</td>
<td>V^+ = 1V, V_C = 0V, R_L = 2 kΩ</td>
<td>27</td>
<td>28</td>
<td>27</td>
<td>28</td>
<td>27</td>
<td>28</td>
<td>23</td>
</tr>
</tbody>
</table>
### Electrical Characteristics $V^+ \rightarrow +5.0V$ (Note 4) unless otherwise stated (Continued)

<table>
<thead>
<tr>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>Min</td>
<td>Typ</td>
<td>Max</td>
<td>Min</td>
<td>Typ</td>
<td>Max</td>
</tr>
<tr>
<td>Output Current Source</td>
<td>$V_O = 2V$</td>
<td>$V_{IN^+} = +1V$, $V_{IN^-} = 0V$, $V^+ = 15V$</td>
<td>10</td>
<td>20</td>
<td>10</td>
<td>20</td>
<td>10</td>
</tr>
<tr>
<td></td>
<td>Sink</td>
<td>$V_{IN^+} = +1V$, $V_{IN^-} = 0V$, $V^+ = 15V$</td>
<td>10</td>
<td>15</td>
<td>5</td>
<td>8</td>
<td>5</td>
</tr>
</tbody>
</table>

**Note 1:** For operating at high temperatures, the LM324/LM324A/LM2902 must be derated based on a $+125^\circ C$ maximum junction temperature and a thermal resistance of $88^\circ C/W$ which applies for the device soldered in a printed circuit board, operating in a still air ambient. The LM224/LM224A and LM124/LM124A can be derated based on a $+150^\circ C$ maximum junction temperature. The dissipation is the total of all four amplifiers—use external resistors, where possible, to allow the amplifier to saturate or to reduce the power which is dissipated in the integrated circuit.

**Note 2:** Short circuits from the output to $V^+$ can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 40 mA independent of the magnitude of $V^+$. At values of supply voltage in excess of $+15V$, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

**Note 3:** This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the $V^+$ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than $-0.9V$ (at $25^\circ C$).

**Note 4:** These specifications are limited to $-55^\circ C \leq T_A \leq +125^\circ C$ for the LM124/LM124A. With the LM224/LM224A, all temperature specifications are limited to $-25^\circ C \leq T_A \leq +85^\circ C$. The LM324/LM324A temperature specifications are limited to $0^\circ C \leq T_A \leq +70^\circ C$, and the LM2902 specifications are limited to $-40^\circ C \leq T_A \leq +85^\circ C$.

**Note 5:** $V_O = 1.4V$, $R_S = 0\Omega$ with $V^+$ from $5V$ to $30V$, and over the full input common-mode range ($0V$ to $V^+$) for LM2902, $V^+$ from $5V$ to $26V$.

**Note 6:** The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

**Note 7:** The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than $0.3V$ (at $25^\circ C$). The upper end of the common-mode voltage range is $V^+ - 1.5V$ (at $25^\circ C$), but either or both inputs can go to $-32V$ without damage ($+26V$ for LM2903), independent of the magnitude of $V^+$. Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.

**Note 8:** Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.

**Note 9:** Refer to RETS124XX for LM124A military specifications and refer to RETS124X for LM124 military specifications.

**Note 10:** Human body model, $1.5\kohm$ in series with $100\pF$.

---

**Schematic Diagram (Each Amplifier)**

![Schematic Diagram](image-url)
Typical Performance Characteristics (LM2902 only)

Application Hints

The LM124 series are op amps which operate with only a single power supply voltage, have true-differential inputs, and remain in the linear mode with an input common-mode voltage of 0 V<sub>DC</sub>. These amplifiers operate over a wide range of power supply voltage with little change in performance characteristics. At 25°C amplifier operation is possible down to a minimum supply voltage of 2.3 V<sub>DC</sub>.

The pinouts of the package have been designed to simplify PC board layouts. Inverting inputs are adjacent to outputs for all of the amplifiers and the outputs have also been placed at the corners of the package (pins 1, 7, 8, and 14). Precautions should be taken to insure that the power supply for the integrated circuit never becomes reversed in polarity or that the unit is not inadvertently installed backwards in a test socket as an unlimited current surge through the resulting forward diode within the IC could cause fusing of the internal conductors and result in a destroyed unit.

Large differential input voltages can be easily accommodated and, as input differential voltage protection diodes are not needed, no large input currents result from large differential input voltages. The differential input voltage may be larger than V<sup>+</sup> without damaging the device. Protection should be provided to prevent the input voltages from going negative more than −0.3 V<sub>DC</sub> (at 25°C). An input clamp diode with a resistor to the IC input terminal can be used.

To reduce the power supply drain, the amplifiers have a class A output stage for small signal levels which converts to class B in a large signal mode. This allows the amplifiers to both source and sink large output currents. Therefore both NPN and PNP external current boost transistors can be used to extend the power capability of the basic amplifiers. The output voltage needs to raise approximately 1 diode drop above ground to bias the on-chip vertical PNP transistor for output current sinking applications.

For ac applications, where the load is capacitively coupled to the output of the amplifier, a resistor should be used, from the output of the amplifier to ground to increase the class A bias current and prevent crossover distortion.

Where the load is directly coupled, as in dc applications, there is no crossover distortion. Capacitive loads which are applied directly to the output of the amplifier reduce the loop stability margin. Values of 50 pF can be accommodated using the worst-case non-inverting unity gain connection. Large closed loop gains or resistive isolation should be used if larger load capacitance must be driven by the amplifier.

The bias network of the LM124 establishes a drain current which is independent of the magnitude of the power supply voltage over the range of from 3 V<sub>DC</sub> to 30 V<sub>DC</sub>. Output short circuits either to ground or to the positive power supply should be of short time duration. Units can be destroyed, not as a result of the short circuit current causing metal fusing, but rather due to the large increase in IC chip dissipation which will cause eventual failure due to excessive junction temperatures. Putting direct short-circuits on more than one amplifier at a time will increase the total IC power dissipation to destructive levels, if not properly protected with external dissipation limiting resistors in series with the output leads of the amplifiers. The larger value of output source current which is available at 25°C provides a larger output current capability at elevated temperatures (see typical performance characteristics) than a standard IC op amp.

The circuits presented in the section on typical applications emphasize operation on only a single power supply voltage. If complementary power supplies are available, all of the standard op amp circuits can be used. In general, introducing a pseudo-ground (a bias voltage reference of V<sup>+</sup>/2) will allow operation above and below this value in single power supply systems. Many application circuits are shown which take advantage of the wide input common-mode voltage range which includes ground. In most cases, input biasing is not required and input voltages which range to ground can easily be accommodated.
Typical Single-Supply Applications ($V^+ = 5.0 \, V_{DC}$)

Non-Inverting DC Gain (0V Input = 0V Output)

*R not needed due to temperature independent $I_{IN}$

DC Summing Amplifier
($V_{IN}$ ≥ 0 $V_{DC}$ and $V_O > V_{DC}$)

Where: $V_O = V_1 + V_2 - V_3 - V_4$

($V_1 + V_2) > (V_3 + V_4)$ to keep $V_O > 0 \, V_{DC}$

Power Amplifier

$V_O = 0 \, V_{DC}$ for $V_{IN} = 0 \, V_{DC}$

$A_V = 10$

LED Driver

"BI-QUAD" RC Active Bandpass Filter

$f_o = 1 \, kHz$
$Q = 50$
$A_v = 100$ (40 dB)
Typical Single-Supply Applications \((V^+ = 5.0 \, V_{DC})\) (Continued)

**Fixed Current Sources**

\[ I_2 = \left(\frac{R_1}{R_2}\right) I_1 \]

**Lamp Driver**

**Current Monitor**

\[ V_0 = \frac{1}{I_1} (V_i - 2V) \]

*Increase R1 for I_L small*

**Driving TTL**

**Voltage Follower**

\[ V_o = V_{in} \]

**Pulse Generator**

\[ 0.001 \, F \]
Typical Single-Supply Applications ($V^+ - 5.0\, V_{DC}$) (Continued)

Squarewave Oscillator

Pulse Generator

High Compliance Current Sink

Low Drift Peak Detector

Comparator with Hysteresis

Ground Referencing a Differential Input Signal

$\text{Io} = 1\, \text{amp/volt}\, V_{IN}$

(Increase $R_E$ for $I_o$ small)
Typical Single-Supply Applications \((V^+ = 5.0 \ V_{DC})\) (Continued)

**Voltage Controlled Oscillator Circuit**

*Wide control voltage range: \(0 \ V_{DC} \leq V_C \leq 2 \ (V^+ - 1.5 \ V_{DC})\)*

**Photo Voltic-Cell Amplifier**

**AC Coupled Inverting Amplifier**

\[ A_v = \frac{R_1}{R_1} \] (As shown, \(A_v = 10\))
Typical Single-Supply Applications \((V^+ - 5.0 \, \text{V}_{\text{DC}})\) (Continued)

**AC Coupled Non-Inverting Amplifier**

\[
A_v = 1 + \frac{R_2}{R_1} \\
A_v = 11 \, \text{(As shown)}
\]

**DC Coupled Low-Pass RC Active Filter**

\[
f_o = 1 \, \text{kHz} \\
Q = 1 \\
A_v = 2
\]

**High Input Z, DC Differential Amplifier**

\[
V_o = 1 + \frac{R_4}{R_3} (V_2 - V_1) \\
\text{As shown: } V_o = 2(V_2 - V_1)
\]
Typical Single-Supply Applications ($V^+ = 5.0\, V_{DC}$) (Continued)

High Input Z Adjustable-Gain DC Instrumentation Amplifier

If $R1 = R5$ & $R3 = R4 = R6 = R7$ (CMRR depends on match)

$V_O = 1 + \frac{R1}{R2} (V_2 - V_1)$

As shown $V_O = 101 (V_2 - V_1)$

Using Symmetrical Amplifiers to Reduce Input Current (General Concept)

Bridge Current Amplifier

For $\delta < 1$ and $R_f > R$

$V_O = V_{REF} \left( \frac{1}{2} \frac{R_f}{R} \right)$

TL/H/9299–29

TL/H/9299–30

TL/H/9299–28
Typical Single-Supply Applications ($V^+ = 5.0 \, V_{DC}$) (Continued)

Bandpass Active Filter

![Bandpass Active Filter Circuit Diagram]

- $f_0 = 1 \, kHz$
- $Q > 25$

TL/H/9299–31
LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.
This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.
National Semiconductor was acquired by Texas Instruments.

This file is the datasheet for the following electronic components: